Fundamentals of Computer Systems Transistors, Gates, and ICs

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Semiconductor

sem·i·con·duc·tor

noun

- 1. a substance, such as silicon or germanium, with electrical conductivity intermediate between that of an insulator and a conductor
- 2. a semiconductor device

Sand into Silicon



Silica a.k.a. SiO_2 a.k.a. Quartz $SiO_2 + 2 C \rightarrow Si + 2 CO$



Elemental, amorphous silicon

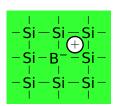


Monocrystalline Silicon Ingot

Doping Silicon Makes It a Better Conductor

Undoped (pure) silicon crystal

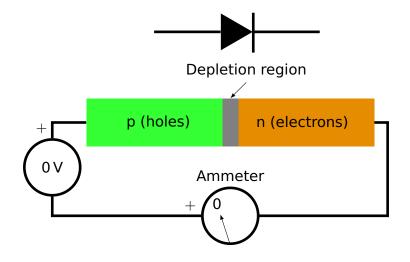
Not a good conductor



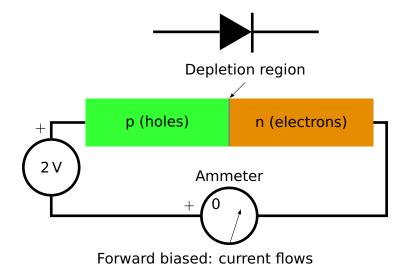
p-type (doped) silicon boron atom steals a nearby electron

n-type (doped)
silicon:
extra electron on
arsenic atom
jump loose

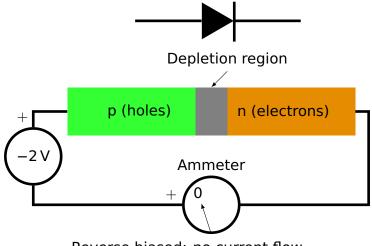
A PN Junction aka A Diode



A PN Junction aka A Diode

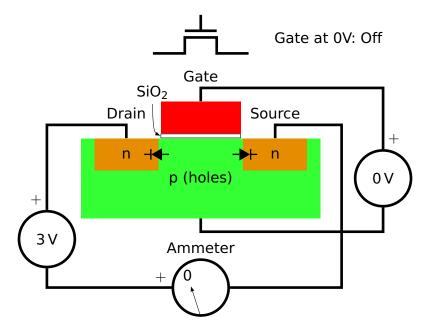


A PN Junction aka A Diode

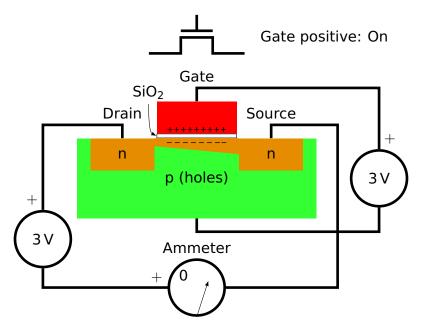


Reverse biased: no current flow

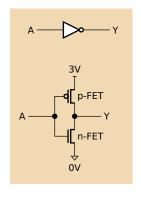
An N-Channel MOS Transistor



An N-Channel MOS Transistor

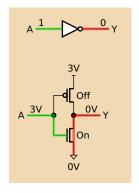


The CMOS Inverter



An inverter is built from two MOSFETs: An n-FET connected to ground A p-FET connected to the power supply

The CMOS Inverter



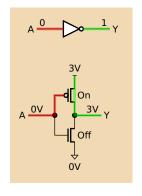
When the input is near the power supply voltage ("1"),

the p-FET is turned off;

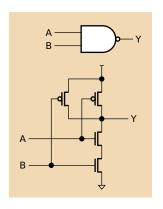
the n-FET is turned on, connecting the output to ground ("0").

n-FETs are only good at passing 0's

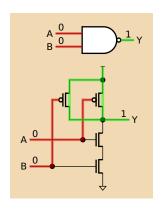
The CMOS Inverter



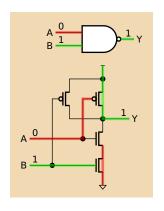
When the input is near ground ("0"), the p-FET is turned on, connecting the output to the power supply ("1"); the n-FET is turned off. p-FETs are only good at passing 1's



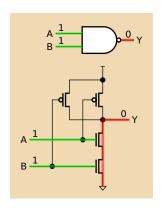
Two-input NAND gate: two n-FETs in series; two p-FETs in parallel



Both inputs 0: Both p-FETs turned on Output pulled high



One input 1, the other 0:
One p-FET turned on
Output pulled high
One n-FET turned on, but does
not control output



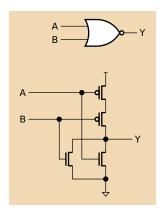
Both inputs 1:

Both n-FETs turned on

Output pulled low

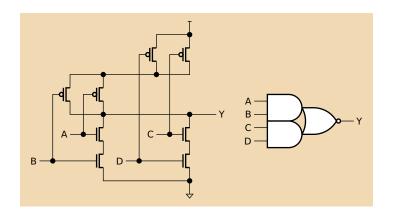
Both p-FETs turned off

The CMOS NOR Gate

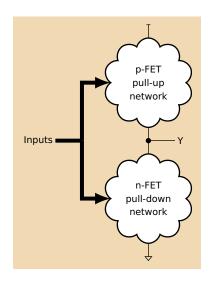


Two-input NOR gate: two n-FETs in parallel; two p-FETs in series. Not as fast as the NAND gate because n-FETs are faster than p-FETs

A CMOS AND-OR-INVERT Gate



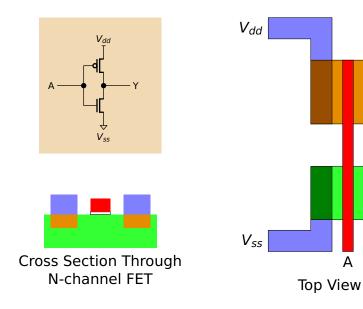
Static CMOS Gate Structure



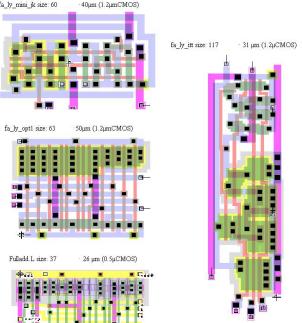
Pull-up and Pull-down networks must be complementary; exactly one should be connected for each input combination.

Series connection in one should be parallel in the other

CMOS Inverter Layout

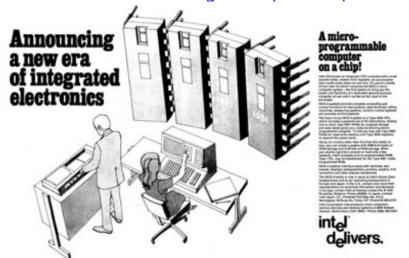


$\begin{array}{ccc} Full \ \ Adder \ \ Layouts \\ {}_{f_a_ly_mini_jk \ size: \ 60} \end{array} \ \ {}_{40\mu m \ (1.2\mu m CMOS)}$



From http://book.huihoo.com/design-of-vlsi-systems/

Intel 4004: The First Single-Chip Microprocessor



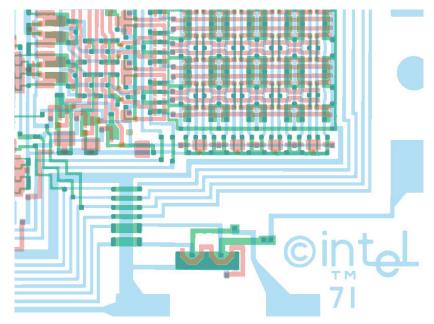
4001: 256-byte ROM + 4-bit IO port

4002: 40-byte RAM

4003: 10-bit shift register

4004: 740 kHz 4-bit CPU w/ 45 instructions (2300 transistors)

Intel 4004 Masks



Intel 4004 Die Photograph

